# Low Voltage, Dual Supply, Low Ron, Quad SPST Analog Switches

## **DESCRIPTION**

The DG9424, DG9425, DG9426 are low voltage precision monolithic quad single-pole-single-throw analog switches.

Using BiCMOS wafer fabrication technology allows the DG9424, DG9425, DG9426 to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with  $\pm$  3 V to  $\pm$  6 V.

Combining high speed ( $t_{ON}$ : 42 ns), flat  $R_{DS(on)}$  over the analog signal range ( $\Omega$ ), minimal insertion lose (-3 dB at 190 MHz), and excellent crosstalk and off-isolation performance, the DG9424, DG9425, DG9426 are ideally suited for audio and video signal switching.

The DG9424 and DG9425 respond to opposite control logic as shown in the truth table. The DG9426 has two normally open and two normally closed switches.

### **FEATURES**

- 2.7 V thru 12 V single supply or ± 3 thru ± 6 dual supply
- On-resistance  $R_{DS(on)}$ : 1.7  $\Omega$
- Fast switching ton: 42 ns
  - t<sub>OFF</sub>: 28 ns
- TTL, CMOS compatible
- Low leakage: 0.2 nA
- 2000 V ESD protection

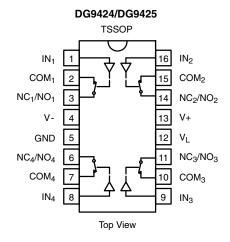
#### **BENEFITS**

- Widest dynamic range
- · Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

#### **APPLICATIONS**

- · Automatic test equipment
- Data acquisition systems
- · Communication systems
- ADC systems
- xDSL and PBX / PABX
- · Audio signal routing

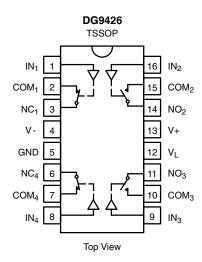
### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE							
LOGIC	DG9424	DG9425					
0	OFF	ON					
1	ON	OFF					

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## **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE							
LOGIC	SW <sub>1</sub> , SW <sub>4</sub>	SW <sub>2</sub> , SW <sub>3</sub>					
0	ON	OFF					
1	OFF	ON					

ORDERING INFORMATION						
TEMP. RANGE	PACKAGE	PART NUMBER				
		DG9424DQ-T1-E3				
-40 °C to +85 °C	16-Pin TSSOP	DG9425DQ-T1-E3				
		DG9426DQ-T1-E3				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	PARAMETER		UNIT				
V+ to V-		-0.3 to +13					
GND to V-		7	V				
V <sub>L</sub>		(GND - 0.3) to (V+) + 0.3	V				
IN, COM, NC, NO <sup>a</sup>		(V-) - 0.3 to (V+) + 0.3					
Continuous Current (NO, NC, COM Pins)	Continuous Current (NO, NC, COM Pins)		Λ				
Peak Current, S or D (Pulsed 1 ms, 10 %	Duty Cycle)	200	mA				
Storage Temperature		-65 to +150	°C				
Power Dissipation (Package) b	16-Pin TSSOP °	450	mW				
Thermal Resistance b	10-PIII 1350P°	178	°C/W				

#### Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 25 °C.



SPECIFICATIONS a Single	e Supply 1	2 V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	12	V
On-Resistance	R <sub>ON</sub>	V+ = 10.8 V, V- = 0 V	Room	-	1.8	3	Ω
On resistance	TION	$I_{NO}$ , $I_{NC} = 50$ mA, $V_{COM} = 2 V / 9 V$	Full	-	-	4	32
Digital Control							
Input Current	$I_{\text{INL}}$ or $I_{\text{INH}}$		Full	-1	0.01	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	tou		Room	-	42	57	
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Full	-	-	65	
Turn-Off Time e	+	$V_{NO}$ , $V_{NC} = 5$ $V$ , see fig. 2	Room	-	28	42	ns
rum-on nime °	LOFF		Full	-	-	44	
Break-Before-Make Time Delay e	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC} = 5 \text{ V}$ $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$	Room	2	-	-	
Charge Injection e	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	38	-	рС
Off-Isolation e	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	-	-77	-	ав
NO NO Off Conscitones 6	C <sub>NO(off)</sub>		Room	-	49	_	
NO, NC Off Capacitance e	C <sub>NC(off)</sub>	f 1 MI I-	Hoom			-	
COM Off Capacitance e	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	37	-	pF
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	-	89	-	
Power Supplies							
Docitive Comply Compant	1.		Room	-	0.02	1	
Positive Supply Current	I+		Full	-	-	5	
Negative Supply Current			Room	-1	-0.002	-	
	l-	$V_{IN} = 0$ or $V_L$	Full	-5	-	-	μΑ
Lania Overalis Overal	IL		Room	-	0.002	1	
Logic Supply Current			Full	-	-	5	
Overved Overved			Room	-1	-0.002	-	
Ground Current	I <sub>GND</sub>		Full	-5	-	-	



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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-5		5	V
On-Resistance	R <sub>ON</sub>	$V_{+} = 4.5 \text{ V}, \ V_{-} = -4.5 \text{ V} \\ I_{NO}, \ I_{NC} = 50 \text{ mA}, \ V_{NO}, \ V_{COM} = \pm \ 3.5 \text{ V}$	Room Full	-	2 -	3.3 4.3	Ω
	I <sub>NO(off)</sub>		Room	-1	-	1	
	I <sub>NC(off)</sub>	V+ = 5.5 V. V- = -5.5 V	Full	-10	-	10	
Switch Off Leakage Current	()	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	
	I <sub>COM(off)</sub>		Full	-10	-	10	nA
Channel On Leakage Current	loow	V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Onarmer on Leakage ourrent	ICOM(on)	$V_{NO}$ , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input Current <sup>a</sup>	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.05	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>		R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room	-	48	67	
Turn-On Time "	t <sub>ON</sub>		Full	-	-	81	ns
Turn-Off Time <sup>e</sup>		$V_{NO}$ , $V_{NC} = \pm 3.5 \text{ V}$ , see fig. 2	Room	=	34	57	
Turn-Oil Tillie	t <sub>OFF</sub>		Full	-	_	67	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	2	-	-	
Charge Injection e	$Q_{INJ}$	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	112	-	рC
Off Isolation <sup>e</sup>	OIRR	D 5000 5 7 1 1 MIL-	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room	-	-82	-	иь
Source Off Capacitance e	C <sub>NO(off)</sub> C <sub>NC(off)</sub>		Room	-	38	-	
Drain Off Capacitance e	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	38	-	pF
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	-	89	-	
Power Supplies				. <u>-</u>	1	1	
Positive Supply Current <sup>e</sup>	I+		Room	-	0.03	1	
. co.are cappi, cuitoni			Full	-	-	5	
Negative Supply Current <sup>e</sup>	I-		Room	-1	-0.002	-	
		$V_{IN} = 0$ or $V_L$	Full	-5	0.000	-	μΑ
Logic Supply Current <sup>e</sup>	ال		Room	-	0.002	1	
			Full	-	-	5	
Ground Current e	I <sub>GND</sub>		Room	-1	-0.002	-	
		Full	-5	=.	-		



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SPECIFICATIONS a Single	e Supply 5	V					ı
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 5 V, $V- = 0 VV_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-	-	5	V
On-Resistance <sup>e</sup>	R <sub>ON</sub>	$V+ = 4.5 \text{ V}, I_{NO}, I_{NC} = 50 \text{ mA},$	Room	-	3.4	4.8	Ω
On-nesistance -	HON	VCOM = 1 V, 3.5 V	Full	-	-	5.8	22
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	+		Room	-	71	86	
rum-on time °	t <sub>ON</sub>	$R_L = 300 \Omega, C_L = 35 pF$	Hot	-	-	106	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC} = 3.5 \text{ V}$ , see fig. 2	Room	-	37	51	ns
rum-On Time °			Hot	-	-	56	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5	-	-	
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, \text{ R}_g = 0 \Omega, \text{ C}_L = 1 \text{ nF}$	Room	-	10	-	рС
Power Supplies							
Desitive Comply Comment 6			Room	-	0.02	1	
Positive Supply Current <sup>e</sup>	I+	Hot	Hot	-	-	5	
Nagative Cumply Current 6	1		Room	-1	-0.002	-	
Negative Supply Current <sup>e</sup>	I-		Hot	-5	-	-	
Logio Supply Current 6	$V_{IN} = 0$ or $V_L$	$V_{IN} = U \text{ or } V_{L}$	Room	-	0.002	1	μA
Logic Supply Current <sup>e</sup>	l∟		Hot	-	-	5	
Cround Courset 6			Room	-1	-0.002	-	
Ground Current <sup>e</sup>	$I_{GND}$		Hot	-5	-	-	



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SPECIFICATIONS a Sing	le Supply 3	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	LIMITS -40 °C to +85 °C			UNIT
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V f$		MIN. d	TYP. c	MAX. d	0
Analog Switch							
Analog Signal Range e	V <sub>ANALOG</sub>		Full	0	-	3	>
On-Resistance	R <sub>ON</sub>	V+ = 2.7 V, V- = 0 V	Room	-	8	13.8	Ω
On ricolatarioc	TION	$I_{NO}$ , $I_{NC} = 5$ mA, $V_{COM} = 0.5$ V, 2.2 V	Full	-	-	15.1	32
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current <sup>a</sup>	I <sub>NC(off)</sub>	V+ = 3.3 V, V- = 0 V	Full	-10	-	10	
Switch on Leakage outrent	1	$V_{COM} = 0.3 \text{ V}, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nA
	I <sub>COM(off)</sub>		Full	-10	-	10	
Channel On Leakage Current a	loour )	V+ = 3.3 V, V- = 0 V,	Room	-1	-	1	
Onamiel On Leakage Ourient	I <sub>COM(on)</sub>	$V_{NO}$ , $V_{NC} = V_{COM} = 0.3 \text{ V}$ , 3 V	Full	-10	-	10	
Digital Control <sup>e</sup>							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	-1	0.005	1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>		Room	-	140	163	
Tam on time	UN	$R_L = 300 \Omega$ , $C_L = 35 pF$	Full	-	-	193	
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC} = 1.5 V$ , see fig. 2	Room	-	65	80	ns
Turr on Time	OFF		Full	-	-	89	
Break-Before-Make Time Delay	t <sub>D</sub>	DG9426 only, $V_{NO}$ , $V_{NC}$ = 1.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5			
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g=0~V,~R_g=0~\Omega,~C_L=1~nF$	Room	-	15	-	рС
Off Isolation e	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	ı	-80	-	u u
Source Off Capacitance e	C <sub>NO(off)</sub>	f = 1 MHz	Room	_	53	_	
Source On Capacitance	C <sub>NC(off)</sub>		HOOIII		33	_	pF
Drain Off Capacitance e	C <sub>COM(off)</sub>	I = I IVIDZ	Room	-	42	-	рг
Channel On Capacitance e	C <sub>COM(on)</sub>		Room	-	92	-	

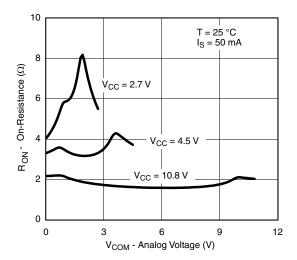
### Notes

- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
- b. Room = 25 °C, Full = As determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = Input voltage to perform proper function.

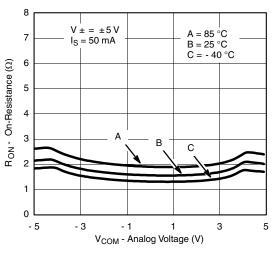
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



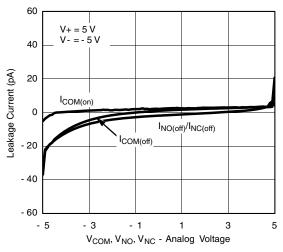
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



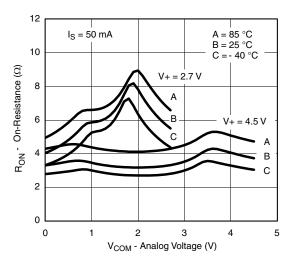
Ron vs. V<sub>COM</sub> and Supply Voltage



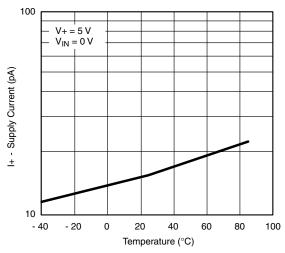
R<sub>ON</sub> vs. Analog Voltage and Temperature



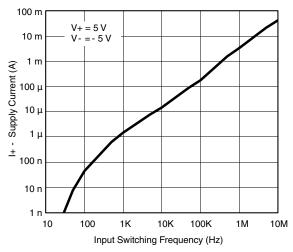
Leakage Current vs. Analog Voltage



R<sub>ON</sub> vs. Analog Voltage and Temperature



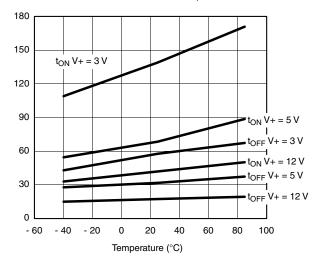
Supply Current vs. Temperature



**Switching Current vs. Input Switching Frequency** 

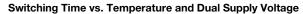
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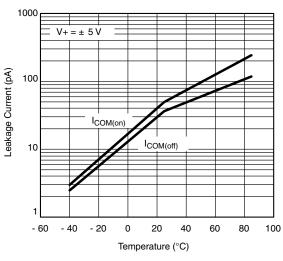
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

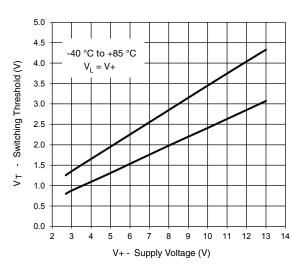


120  $V_{SUPPLY} = \pm 5 V$ 100 80 60  $t_{ON} V_S = -3.5 V$  $t_{ON} V_{S} = 3.5 V$ 40  $t_{OFF} V_S = -3.5 V$  $t_{OFF} V_S = 3.5 V$ 20 - 60 - 40 - 20 0 20 40 60 80 100 Temperature (°C)

Switching Time vs. Temperature and Single Supply Voltage

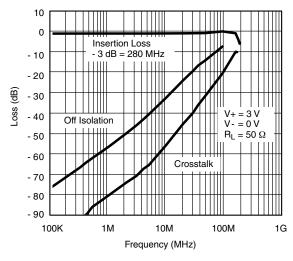






Leakage Current vs. Temperature

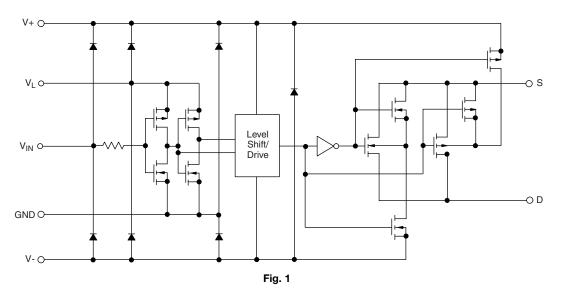
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency



## **SCHEMATIC DIAGRAM** (typical channel)



## **TEST CIRCUITS**

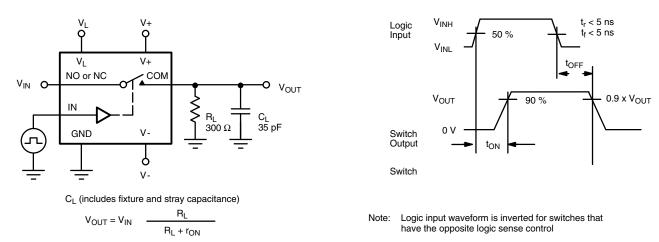


Fig. 2 - Switching Time

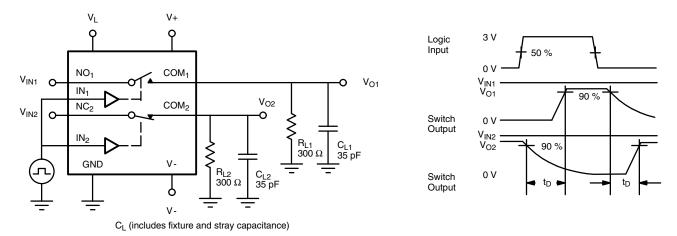


Fig. 3 - Break-Before-Make (DG9426)

 $\Delta V_{O}$ 

OFF

OFF

## **TEST CIRCUITS**

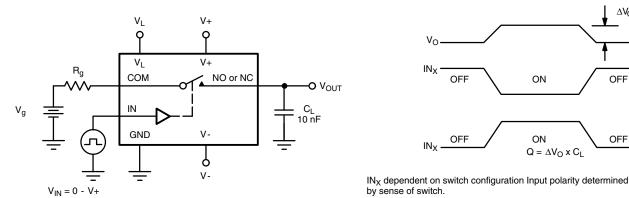


Fig. 4 - Charge Injection

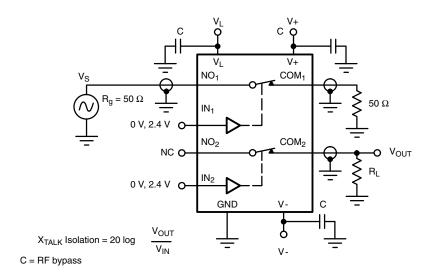


Fig. 5 - Crosstalk

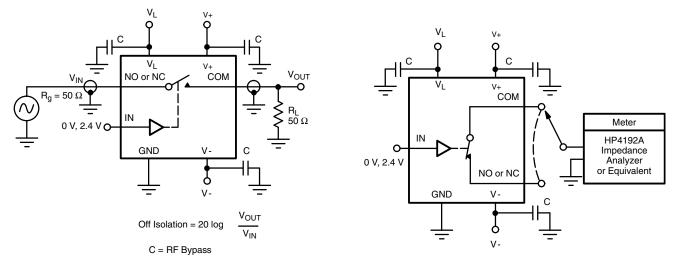


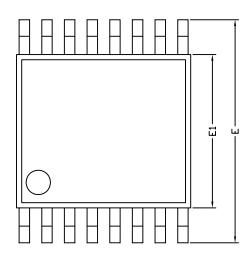
Fig. 6 - Off-Isolation

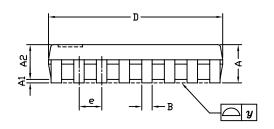
Fig. 7 - Source / Drain Capacitances

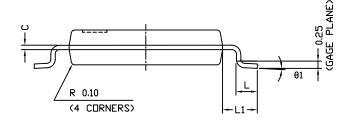
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**TSSOP: 16-LEAD** 







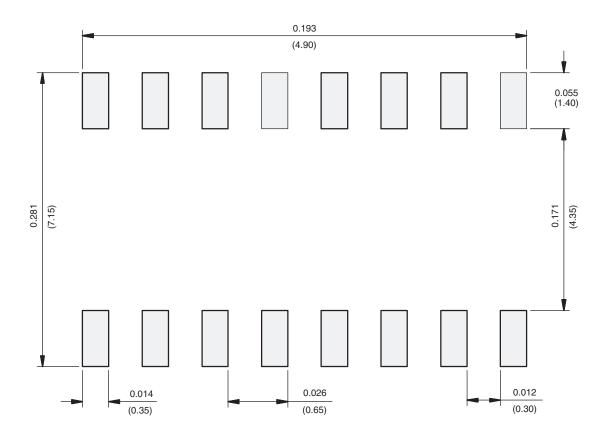
	DI	MENSIONS IN MILLIMETE	RS
Symbols	Min	Nom	Max
Α	-	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D. 23-0	Oct-06		

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



## **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)

## **Legal Disclaimer Notice**



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